

BCP56-10TF Datasheet

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DiGi Electronics Part Number BCP56-10TF-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BCP56-10TF

Description TRANS NPN 80V 1A SOT223

Detailed Description Bipolar (BJT) Transistor NPN 80 V 1 A 100MHz 1.8 W

Surface Mount SOT-223



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Purchase and inquiry

| Manufacturer Product Number: | Manufacturer: |
|--|--|
| BCP56-10TF | Nexperia USA Inc. |
| Series: | Product Status: |
| - | Active |
| Transistor Type: | Current - Collector (Ic) (Max): |
| NPN | 1 A |
| Voltage - Collector Emitter Breakdown (Max): | Vce Saturation (Max) @ lb, lc: |
| 80 V | 500mV @ 50mA, 500mA |
| Current - Collector Cutoff (Max): | DC Current Gain (hFE) (Min) @ Ic, Vce: |
| 100nA (ICBO) | 63 @ 150mA, 2V |
| Power - Max: | Frequency - Transition: |
| 1.8 W | 100MHz |
| Operating Temperature: | Grade: |
| 150°C (TJ) | Automotive |
| Qualification: | Mounting Type: |
| AEC-Q101 | Surface Mount |
| Package / Case: | Supplier Device Package: |
| TO-261-4, TO-261AA | SOT-223 |
| Base Product Number: | |
| BCP56 | |

Environmental & Export classification

| RoHS Status: | Moisture Sensitivity Level (MSL): |
|------------------|-----------------------------------|
| ROHS3 Compliant | 1 (Unlimited) |
| REACH Status: | ECCN: |
| REACH Unaffected | EAR99 |
| HTSUS: | |
| 8541.29.0075 | |

BCP56T series

80 V, 1 A NPN medium power transistors Rev. 3 — 1 July 2022

Product data sheet

1. General description

NPN medium power transistors in a medium power SOT223 (SC73) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

| Type number | Package | PNP complement | |
|-------------|----------|----------------|-----------|
| | Nexperia | JEDEC | |
| BCP56T | SOT223 | SC-73 | BCP53T |
| BCP56-10T | | | BCP53-10T |
| BCP56-16T | | | BCP53-16T |

2. Features and benefits

- High collector current capability I_{C} and I_{CM}
- Three current gain selections
- High power dissipation capability

3. Applications

- Linear voltage regulators
- MOSFET drivers
- High-side switches
- Power management
- Amplifiers

4. Quick reference data

Table 2. Quick reference data

 T_{amb} = 25 °C unless otherwise specified.

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-----------------|---------------------------|--|-----|-----|-----|-----|------|
| V_{CEO} | collector-emitter voltage | open base | | - | - | 80 | V |
| I _C | collector current | | | - | - | 1 | Α |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | | - | - | 2 | А |
| h _{FE} | DC current gain | | | • | | | |
| | BCP56T | V _{CE} = 2 V; I _C = 150 mA | [1] | 63 | - | 250 | |
| | BCP56-10T | | [1] | 63 | - | 160 | |
| | BCP56-16T | | [1] | 100 | - | 250 | |

[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$



5. Pinning information

Table 3. Pinning

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|----------------------------------|----------------|
| 1 | В | base | 4 | С |
| 2 | С | collector | | |
| 3 | E | emitter | | B— |
| 4 | С | collector | ∃ 1 ∃ 2 ∃ 3 | Ė |
| | | | | sym123 |

6. Ordering information

Table 4. Ordering information

| Type number | Package | ackage | | | |
|-------------|---------|---|---------|--|--|
| | Name | Description | Version | | |
| BCP56T | SC-73 | plastic, surface-mounted package with increased heatsink; | SOT223 | | |
| BCP56-10T | | 4 leads | | | |
| BCP56-16T | | | | | |

7. Marking

Table 5. Marking

| Type number | Marking code |
|-------------|--------------|
| BCP56T | BCP56T |
| BCP56-10T | P5610T |
| BCP56-16T | P5616T |

2/15

8. Limiting values

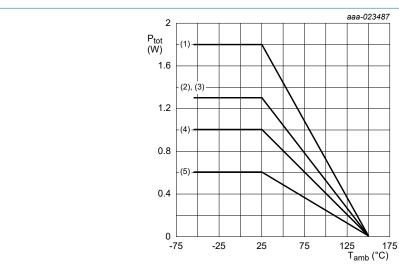
Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

T_{amb} = 25 °C unless otherwise specified.

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|---------------------------|-------------------------------------|-----|-----|-----|------|
| V _{CBO} | collector-base voltage | open emitter | | - | 100 | V |
| V _{CEO} | collector-emitter voltage | open base | | - | 80 | V |
| V _{EBO} | emitter-base voltage | open collector | | - | 5 | V |
| I _C | collector current | | | - | 1 | А |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | | - | 2 | Α |
| l _Β | base current | | | - | 0.2 | Α |
| I _{BM} | peak base current | single pulse; t _p ≤ 1 ms | | - | 0.3 | А |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 0.6 | W |
| | | | [2] | - | 1 | W |
| | | | [3] | - | 1.3 | W |
| | | | [4] | - | 1.3 | W |
| | | | [5] | - | 1.8 | W |
| Tj | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -55 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm².
- [3] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 6 cm².
- [4] Device mounted on an FR4 Printed-Circuit-Board (PCB), 4-layer copper; tin-plated and standard footprint.
- [5] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated; mounting pad for collector 1 cm.²



- (1) FR4 PCB; 4-layer copper; 1 cm²
- (2) FR4 PCB; single-sided copper; 6 cm²
- (3) FR4 PCB; 4-layer copper; standard footprint
- (4) FR4 PCB; single-sided copper; 1 cm²
- (5) FR4 PCB; single-sided copper; standard footprint

Fig. 1. Power derating curves

80 V, 1 A NPN medium power transistors

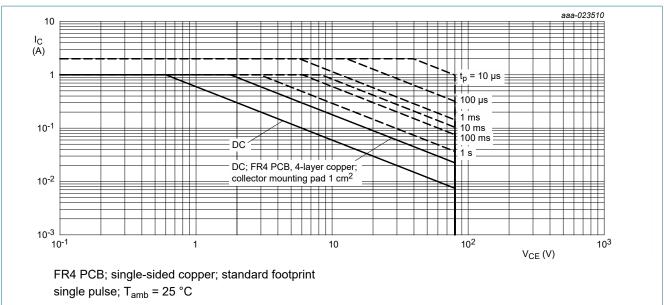


Fig. 2. Safe operating area; junction to ambient; continous and peak collector currents as a funtion of collecoremitter voltage

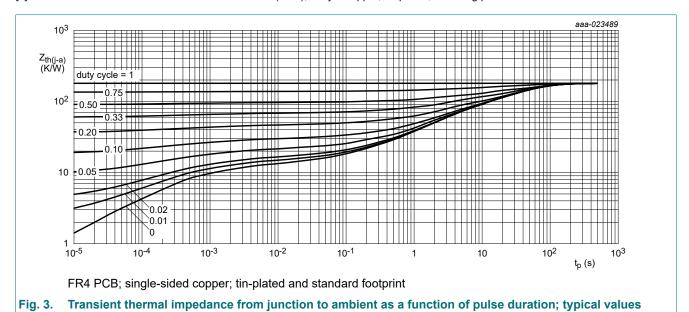
9. Thermal characteristics

Table 7. Thermal characteristics

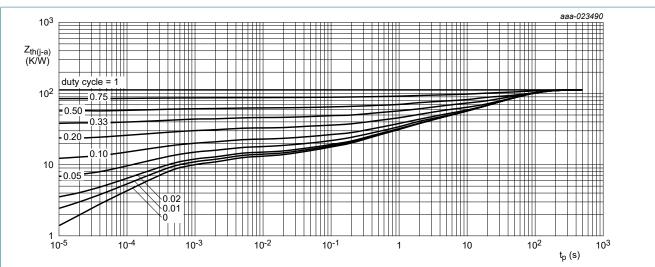
 T_{amb} = 25 °C unless otherwise specified.

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|----------------------|--|-------------|-----|-----|-----|-----|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | [1] | - | - | 209 | K/W |
| | | | [2] | | | 125 | K/W |
| | | | [3] | | | 97 | K/W |
| | | | [4] | - | - | 97 | K/W |
| | | | [5] | - | - | 70 | K/W |
| R _(j-sp) | thermal resistance from junction to solder point | | | - | - | 18 | K/W |

- Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm². Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 6 cm². [3]
- Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint.
- Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated; mounting pad for collector 1 cm². [5]

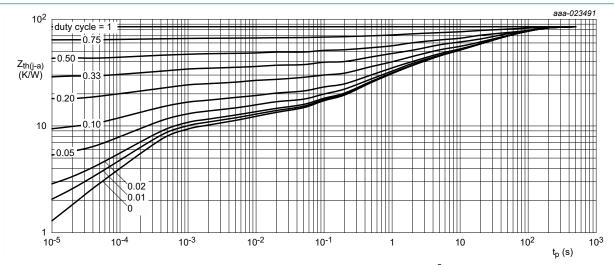


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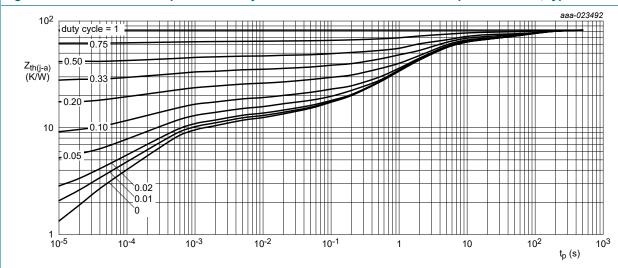
FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm²

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 6 cm²

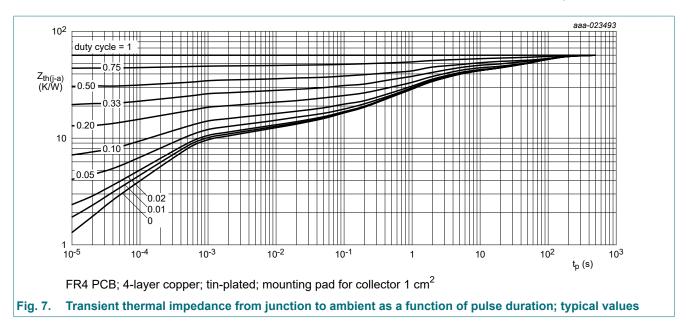
Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; 4-layer copper; tin-plated and standard footprint

Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

80 V, 1 A NPN medium power transistors



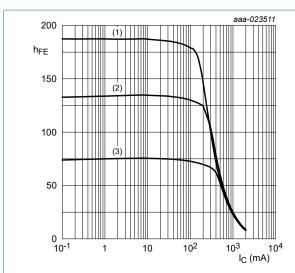
10. Characteristics

Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|----------------------|--|--|---|-----|-----|-----|------|
| V _{(BR)CBO} | collector-base breakdown voltage | $I_C = 100 \ \mu A; I_E = 0 \ A$ | | 100 | - | - | V |
| V _{(BR)CEO} | collector-emitter breakdown voltage | I _C = 2 mA; I _B = 0 A | I _C = 2 mA; I _B = 0 A | | - | - | V |
| V _{(BR)EBO} | emitter-base breakdown voltage | I _E = 100 μA; I _C = 0 A | | 5 | - | - | V |
| I _{CBO} | collector-base | V _{CB} = 30 V; I _E = 0 A | | - | - | 100 | nA |
| | cut-off current | V _{CB} = 30 V; I _E = 0 A; T _j = 150 °C | | - | - | 10 | μΑ |
| I _{EBO} | emitter-base cut-off current | V _{EB} = 5 V; I _C = 0 A | | - | - | 100 | nA |
| h _{FE} | DC current gain | | | ' | ' | ' | |
| BCP56T | V _{CE} = 2 V; I _C = 5 mA | [1] | 63 | - | - | | |
| | V _{CE} = 2 V; I _C = 150 mA | [1] | 63 | - | 250 | | |
| | | V _{CE} = 2 V; I _C = 500 mA | [1] | 40 | - | - | |
| | BCP56-10T | V _{CE} = 2 V; I _C = 5 mA | [1] | 63 | - | - | |
| | | V _{CE} = 2 V; I _C = 150 mA | [1] | 63 | - | 160 | |
| | | V _{CE} = 2 V; I _C = 500 mA | [1] | 40 | - | - | |
| | BCP56-16T | V _{CE} = 2 V; I _C = 5 mA | [1] | 63 | - | - | |
| | | V _{CE} = 2 V; I _C = 150 mA | [1] | 100 | - | 250 | |
| | | V _{CE} = 2 V; I _C = 500 mA | [1] | 40 | - | - | |
| V _{CEsat} | collector-emitter saturation voltage | I _C = 500 mA; I _B = 50 mA | [1] | - | - | 500 | mV |
| V _{BE} | base-emitter voltage | V _{CE} = 2 V; I _C = 500 mA | [1] | - | - | 1 | V |
| C _c | collector capacitance | V _{CB} = 10 V; I _E = i _e = 0 A; f = 1 MHz | | - | 4.5 | - | pF |
| f _T | transition frequency | V _{CE} = 5 V; I _C = 50 mA; f = 100 MHz | | 100 | 155 | - | MHz |

^[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$

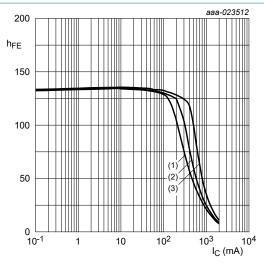


$$V_{CE} = 2 V$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 8. DC current gain as a function of collector current; typical values



(1)
$$V_{CE} = 1 V$$

(2)
$$V_{CE} = 2 V$$

(3)
$$V_{CE} = 5 V$$

Fig. 9. DC current gain as a function of collector current; typical values

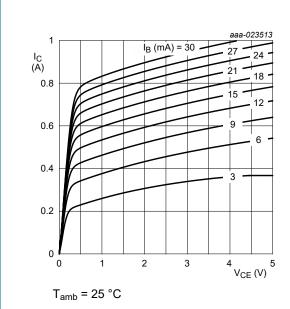
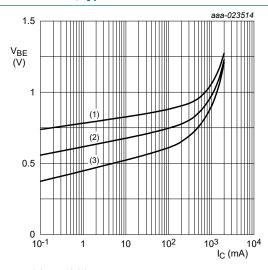


Fig. 10. Collector current as a function of collectoremitter voltage; typical values



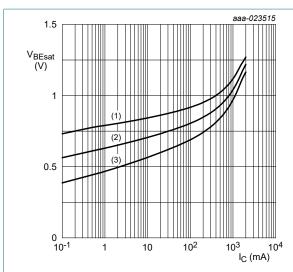
$$V_{CE} = 2 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 11. Base-emitter voltage as a function of collector current; typical values



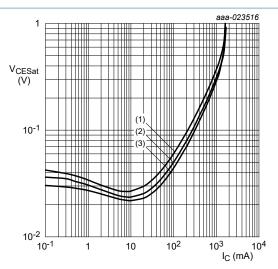
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 100 \, ^{\circ}C$$



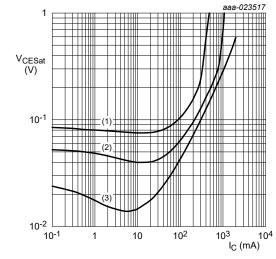


$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

function of collector current; typical values



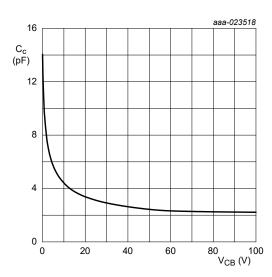
 T_{amb} = 25 °C

(1)
$$I_C/I_B = 50$$

(2)
$$I_C/I_B = 20$$

(3)
$$I_C/I_B = 5$$

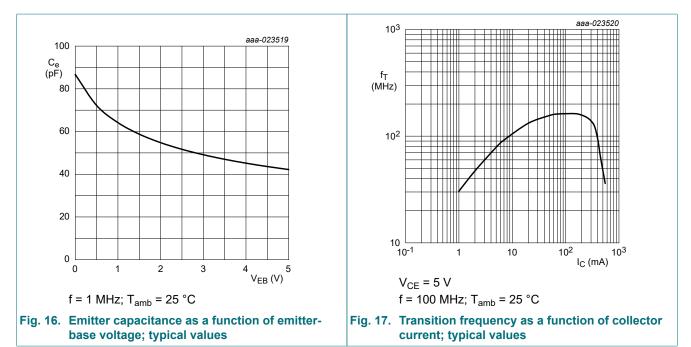
Fig. 14. Collector-emitter saturation voltage as a function of collector current; typical values



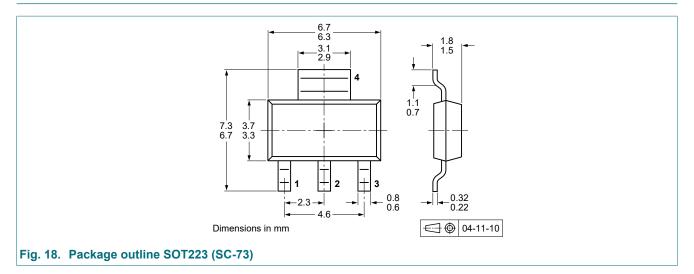
 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ °C}$

Fig. 15. Collector capacitance as a function of collectorbase voltage; typical values

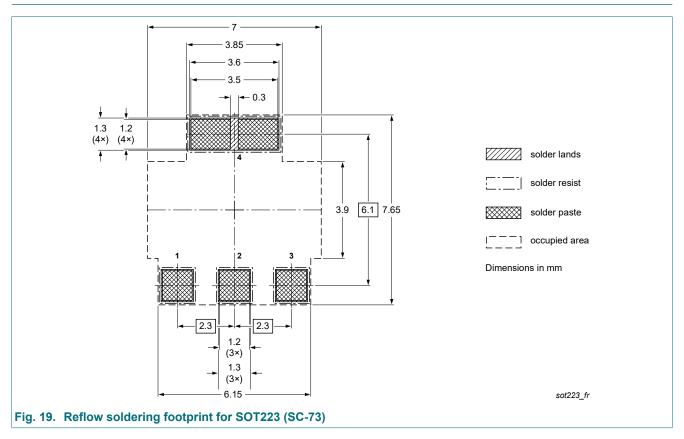
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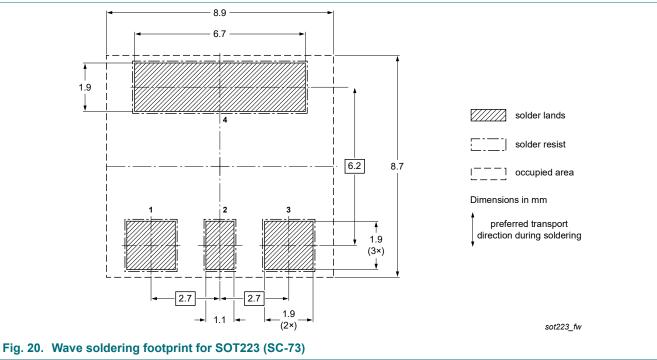


11. Package outline



12. Soldering





BCP56T series

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13. Revision history

Table 9. Revision history

| Tuble 6. Revision motory | | | | | |
|--------------------------|--|--------------------|---------------|----------------|--|
| Document ID | Release date | Data sheet status | Change notice | Supersedes | |
| BCP56T_SER v.3 | 20220701 | Product data sheet | - | BCP56T_SER v.2 | |
| Modifications: | Product(s) changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s). | | | | |
| BCP56T_SER v.2 | 20190429 | Product data sheet | - | BCP56T_SER v.1 | |
| BCP56T_SER v.1 | 20160705 | Product data sheet | - | - | |

14. Legal information

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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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| Product [short] data sheet | Production | This document contains the product specification. |

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Date of release: 1 July 2022

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